

MC79MXX

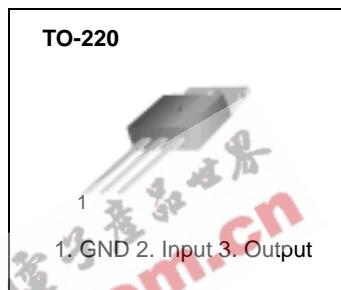
3-Terminal 0.5A Negative Voltage Regulator

Features

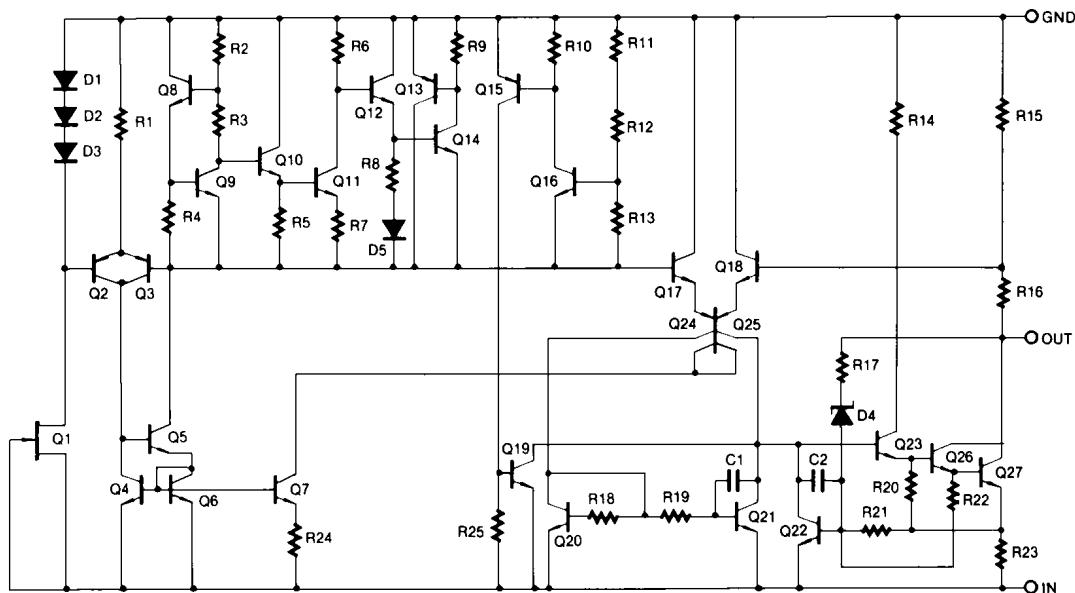
- No external components required
- Output current in excess of 0.5A
- Internal thermal overload
- Internal short circuit current limiting
- Output transistor safe area compensation
- Output voltages of -5V, -6V, -8V, -12V, -15V, -18V and -24V

Description

The MC79MXX series of 3-Terminal medium current negative voltage regulators are monolithic integrated circuits designed as fixed voltage regulators. These regulators employ internal current limiting, thermal shutdown and safe area compensation making them essentially indestructible.



Schematic Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage(for $V_O = -5V$ to $-18V$) (for $V_O = -24V$)	V_I	-35	V
	V_I	-40	V
Thermal Resistance Junction-Cases	$R_{\theta JC}$	5	$^{\circ}C / W$
Thermal Resistance Junction-Air	$R_{\theta JA}$	65	$^{\circ}C / W$
Operating Temperature Range	T_{OPR}	0 ~ +125	$^{\circ}C$
Storage Temperature Range	T_{STG}	-65 ~ +125	$^{\circ}C$

Electrical Characteristics (MC79M05)

(Refer to test circuit, $0^{\circ}C \leq T_J \leq +125^{\circ}C$, $I_O = 350mA$, $V_I = -10V$, unless otherwise specified, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}C$		-4.8	-5	-5.2	V
		$I_O = 5mA$ to $350mA$ $V_I = -7V$ to $-25V$		-4.75	-5	-5.25	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}C$	$V_I = -7V$ to $-25V$	-	7.0	50	mV
			$V_I = -8V$ to $-25V$	-	2.0	30	
Load Regulation (Note1)	ΔV_O	$I_O = 5mA$ to $500mA$ $T_J = +25^{\circ}C$		-	30	100	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}C$		-	3.0	6.0	mA
Quiescent Current Change	ΔI_Q	$I_O = 5mA$ to $350mA$		-	-	0.4	mA
		$I_O = 200mA$ $V_I = -8V$ to $-25V$		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5mA$		-	-0.2	-	mV/ $^{\circ}C$
Output Noise Voltage	V_N	$f = 10Hz, 100KHz$ $T_A = +25^{\circ}C$		-	40	-	μV
Ripple Rejection	RR	$f = 120Hz$ $V_J = -8$ to $-18V$		54	60	-	dB
Dropout Voltage	V_D	$T_J = +25^{\circ}C$, $I_O = 500mA$		-	1.1	-	V
Short Circuit Current	I_{SC}	$T_J = +25^{\circ}C$, $V_I = -35V$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}C$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M06)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -11\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		- 5.75	- 6.0	- 6.25	V
		$I_O = 5\text{mA}$ to 350mA	$V_I = -8\text{V}$ to -25V	- 5.7	- 6.0	- 6.3	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -8\text{V}$ to -25V	-	7.0	60	mV
			$V_I = -9\text{V}$ to -19V	-	2.0	40	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	120	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -8\text{V}$ to -25V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	0.4	-	mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	50	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -9\text{V}$ to -19V		54	60	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M08)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -14\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		- 7.7	- 8.0	- 8.3	V
		$I_O = 5\text{mA}$ to 350mA $V_I = -10.5\text{V}$ to -25V		- 7.6	- 8.0	- 8.4	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -10.5\text{V}$ to -25V	-	7.0	80	mV
			$V_I = -11\text{V}$ to -21V	-	2.0	50	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	160	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -8\text{V}$ to -25V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	-0.6	-	mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	60	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -9\text{V}$ to -19V		54	59	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M12)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -19\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		-11.5	-12	-12.5	V
		$I_O = 5\text{mA}$ to 350mA	$V_I = -14.5\text{V}$ to -30V	-11.4	-12	-12.6	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -14.5\text{V}$ to -30V	-	8.0	80	mV
			$V_I = -15\text{V}$ to -25V	-	3.0	50	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	240	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -14.5\text{V}$ to -30V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	-0.8	-	mV/°C
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	75	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -15\text{V}$ to -25V		54	60	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M15)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -23\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		- 14.4	- 15	- 15.6	V
		$I_O = 5\text{mA}$ to 350mA $V_I = -17.5\text{V}$ to -30V		-14.25	- 15	-15.75	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -17.5\text{V}$ to -30V	-	9.0	80	mV
			$V_I = -18\text{V}$ to -28V	-	5.0	50	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	240	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -17.5\text{V}$ to -28V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	-1.0	-	mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	90	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -18.5\text{V}$ to -28.5V		54	59	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M18)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -27\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		- 17.3	- 18	- 18.7	V
		$I_O = 5\text{mA}$ to 350mA $V_I = -21\text{V}$ to -33V		- 17.1	- 18	- 18.9	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -21\text{V}$ to -33V	-	9.0	80	mV
			$V_I = -24\text{V}$ to -30V	-	5.0	80	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	360	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -21\text{V}$ to -33V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	-1.0	-	mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	110	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -22\text{V}$ to -32V		54	59	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics (MC79M24)

(Refer to test circuit, $0^{\circ}\text{C} \leq T_J \leq +125^{\circ}\text{C}$, $I_O = 350\text{mA}$, $V_I = -33\text{V}$, unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Output Voltage	V_O	$T_J = +25^{\circ}\text{C}$		- 23	- 24	- 25	V
		$I_O = 5\text{mA}$ to 350mA $V_I = -27\text{V}$ to -38V		- 22.8	- 24	- 25.2	
Line Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$V_I = -27\text{V}$ to -38V	-	9.0	80	mV
			$V_I = -30\text{V}$ to -36V	-	5.0	70	
Load Regulation (Note1)	ΔV_O	$T_J = +25^{\circ}\text{C}$	$I_O = 5.0\text{mA}$ to 500mA	-	30	300	mV
Quiescent Current	I_Q	$T_J = +25^{\circ}\text{C}$		-	3	6	mA
Quiescent Current Change	ΔI_Q	$I_O = 5\text{mA}$ to 350mA		-	-	0.4	mA
		$V_I = -27\text{V}$ to -38V		-	-	0.4	
Output Voltage Drift	$\Delta V_O/\Delta T$	$I_O = 5\text{mA}$		-	-1.0	-	mV/ $^{\circ}\text{C}$
Output Noise Voltage	V_N	$f = 10\text{Hz}$ to 100KHz , $T_A = +25^{\circ}\text{C}$		-	180	-	μV
Ripple Rejection	RR	$f = 120\text{Hz}$, $V_I = -28\text{V}$ to -38V		54	58	-	dB
Dropout Voltage	V_D	$I_O = 500\text{mA}$, $T_J = +25^{\circ}\text{C}$		-	1.1	-	V
Short Circuit Current	I_{SC}	$V_I = -35\text{V}$, $T_J = +25^{\circ}\text{C}$		-	140	-	mA
Peak Current	I_{PK}	$T_J = +25^{\circ}\text{C}$		-	650	-	mA

Note:

1. Load and line regulation are specified at constant junction temperature. Change in V_O due to heating effects must be taken into account separately. Pulse testing with low duty is used.

Typical Applications

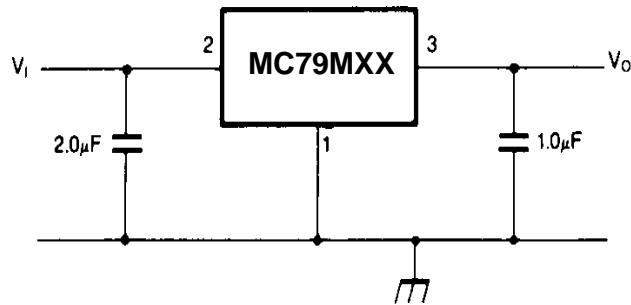


Figure 1. Fixed Output Regulator

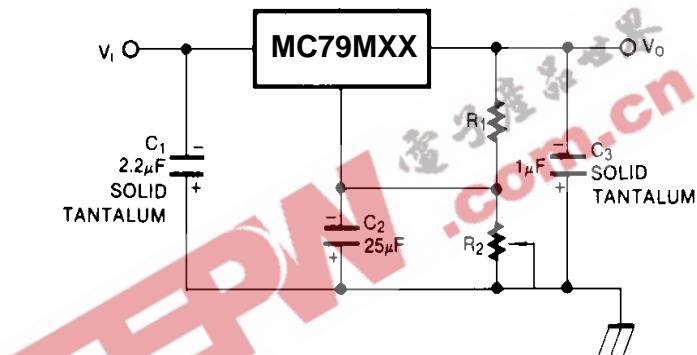


Figure 2. Variable Output

Notes:

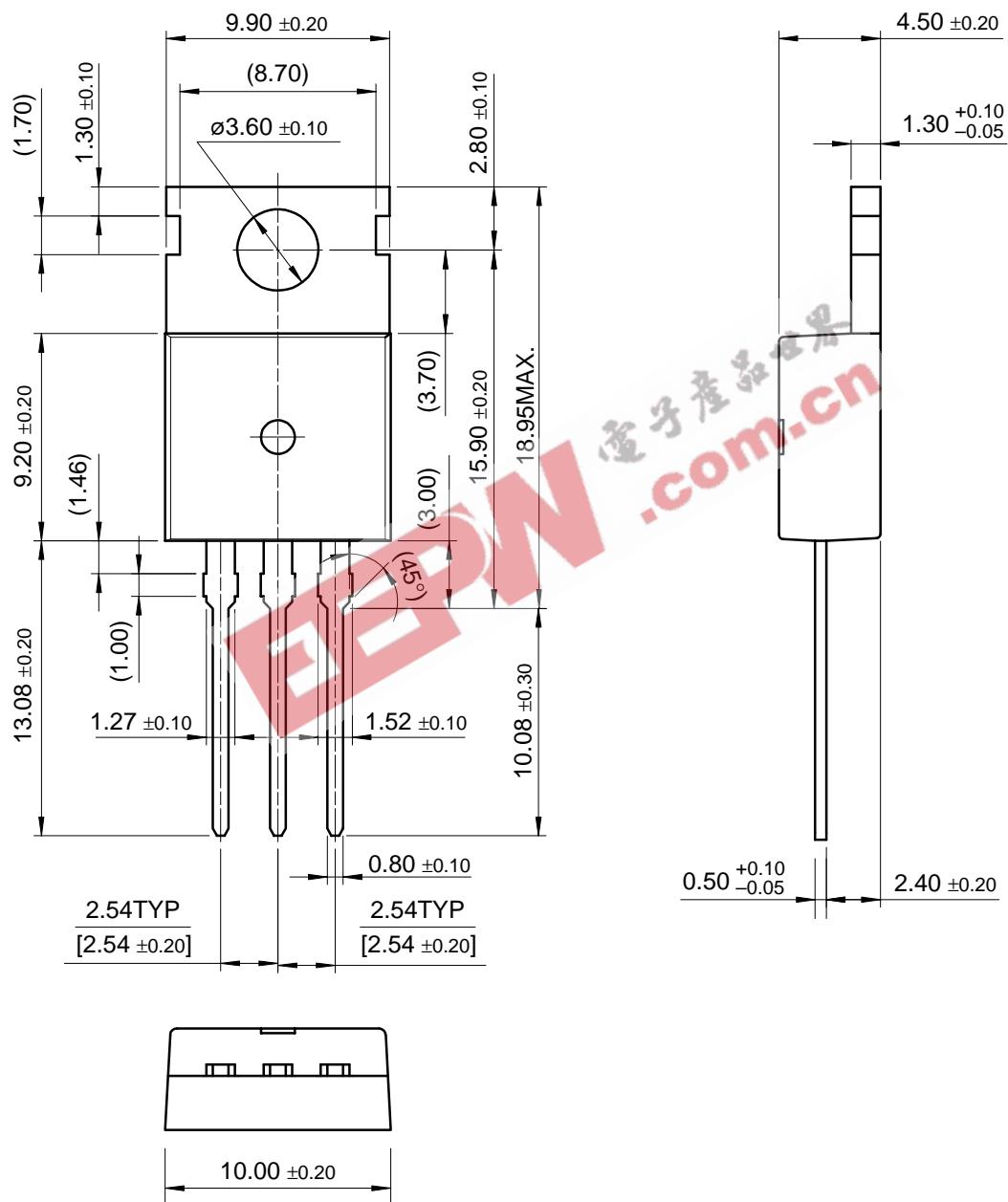
1. Required for stability. For value given, capacitor must be solid tantalum. $25\mu F$ aluminum electrolytic may be substituted.
2. C_2 improves transient response and ripple rejection. Do not increase beyond $50\mu F$.

Mechanical Dimensions

Package

Dimensions in millimeters

TO-220

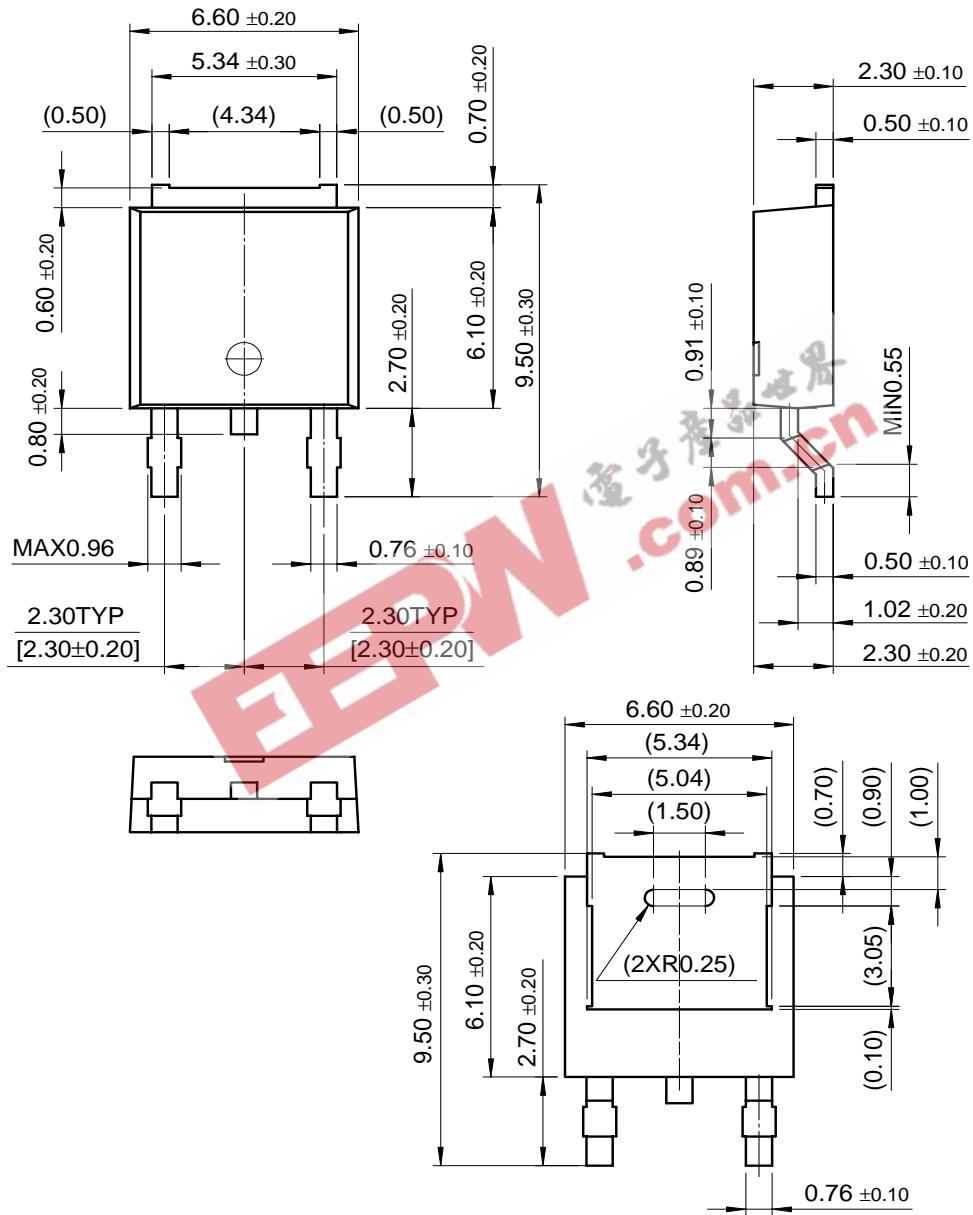


Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

D-PAK



Ordering Information

Product Number	Package	Operating Temperature
MC79M05CT	TO-220	0 ~ + 125°C
MC79M06CT		
MC79M08CT		
MC79M12CT		
MC79M15CT		
MC79M18CT		
MC79M24CT		

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